

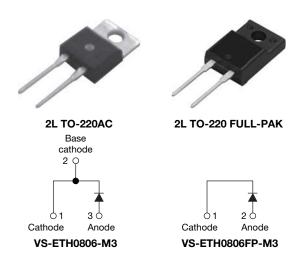
Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

### Hyperfast Rectifier, 8 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I <sub>F(AV)</sub>	8 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub>	2.65 V				
t <sub>rr</sub> (typ.)	16 ns				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				

#### **FEATURES**

- · Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47



Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 146 °C	. 8	А		
FULL-PAK		T <sub>C</sub> = 114 °C	0			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	80			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.					
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.0	2.65	65 V	
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.3	1.85		
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	0.02	12		
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	15	100	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	6	=	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

## VS-ETH0806-M3, VS-ETH0806FP-M3

# Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	16	23	
Povorce receven time		$I_F = 8 \text{ A}, dI_F/dt = 10$	$I_F = 8 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		20	28	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	21	-	ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 390 V	-	39	-	
Dools rooms ourrent		T <sub>J</sub> = 25 °C		-	3	-	Α
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	5	-	_ ^
Deviage weeklen, charge		T <sub>J</sub> = 25 °C		-	36	-	5
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	108	-	nC
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 8 A	-	30	-	ns
Peak recovery current	I <sub>RRM</sub>		T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 600 A/μs	-	13	-
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	205	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C	
Thermal resistance,	В		-	2.0	2.6		
junction to case FULL-PAK	$R_{thJC}$		-	4.6	5.5		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-		
Maight			-	2	-	g	
Weight			-	0.07	-	OZ.	
Mounting torque			6	_	12	kgf · cm	
Woulding torque			(5)		(10)	(lbf · in)	
Marking device		Case style 2L TO-220AC ETH0806		0806	·		
IVIAI NII IY UEVICE		Case style 2L TO-220 FULL-PAK		ETH0	806FP	-	



# Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

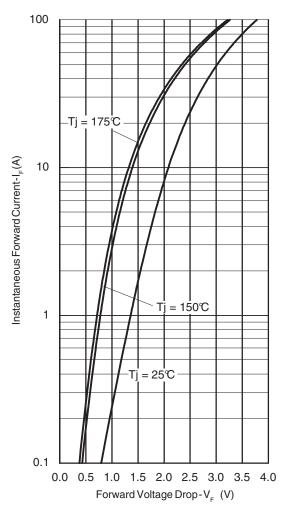


Fig. 1 - Typical Forward Voltage Drop Characteristics

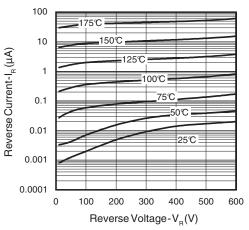


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

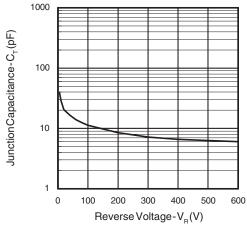


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

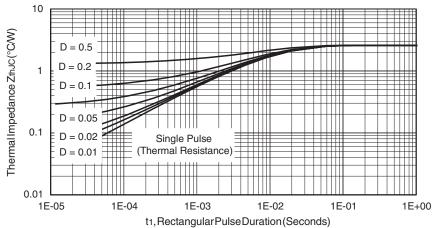


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

### Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



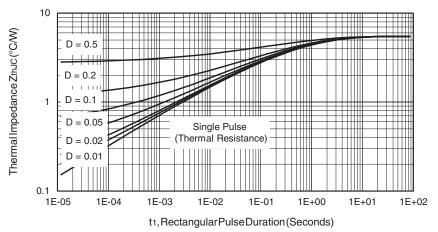


Fig. 5 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (FULL-PAK)

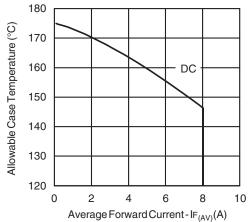


Fig. 6 - Maximum Allowable Case Temperature vs.
Average Forward Current

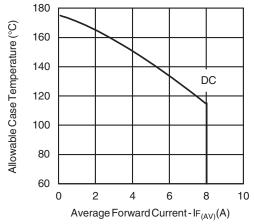


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

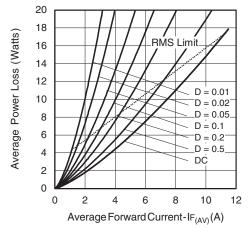


Fig. 8 - Forward Power Loss Characteristics





#### Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

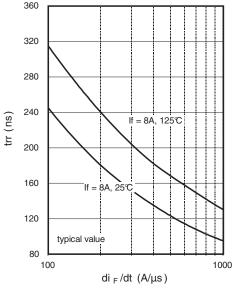


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

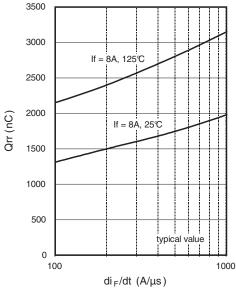


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

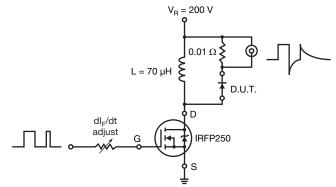
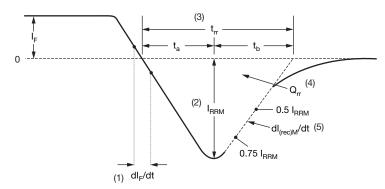


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.
- (4) Q<sub>rr</sub> area under curve defined by t<sub>rr</sub> and I<sub>RRM</sub>
- (5)  $dI_{(rec)M}/dt$  peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 12 - Reverse Recovery Waveform and Definitions

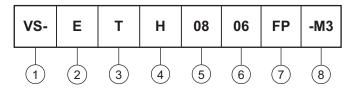
## VS-ETH0806-M3, VS-ETH0806FP-M3

Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = Single diode

**3** - T = TO-220

4 - H = Hyperfast recovery time

5 - Current code: 08 = 8 A

Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

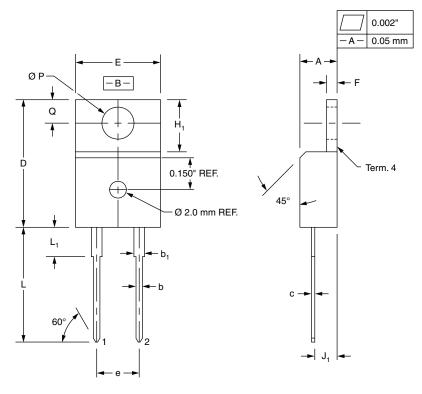
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETH0806-M3	50	1000	Antistatic plastic tube			
VS-ETH0806FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?95259			
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			

Vishay High Power Products

### True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
е	5.08	BSC	0.200 BSC	
F	1.22	1.37	0.048	0.054
H <sub>1</sub>	5.97	6.47	0.235	0.255
J <sub>1</sub>	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150
ØР	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

#### Notes

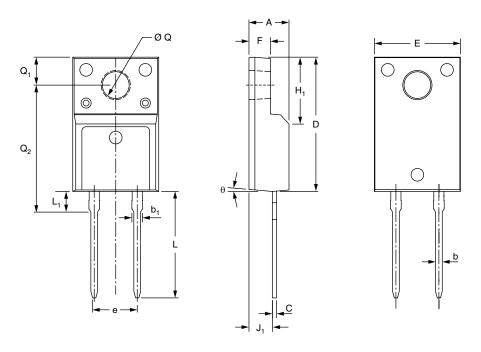
- (1) Lead dimension and finish uncontrolled in L<sub>1</sub>
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- · Controling dimension: Inch



Vishay High Power Products

### True 2 Pin TO-220 FULL-PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	METERS	INCH	ES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08 t	5.08 typical 0.200 typical		pical
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
Q <sub>2</sub>	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°





Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com Revision: 11-Mar-11